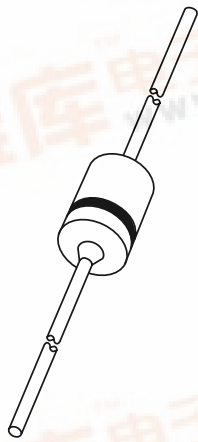


DISCRETE SEMICONDUCTORS

DATA SHEET



BZX79 series **Voltage regulator diodes**

Product specification
Supersedes data of 1999 May 25

2002 Feb 27

Voltage regulator diodes

BZX79 series

FEATURES

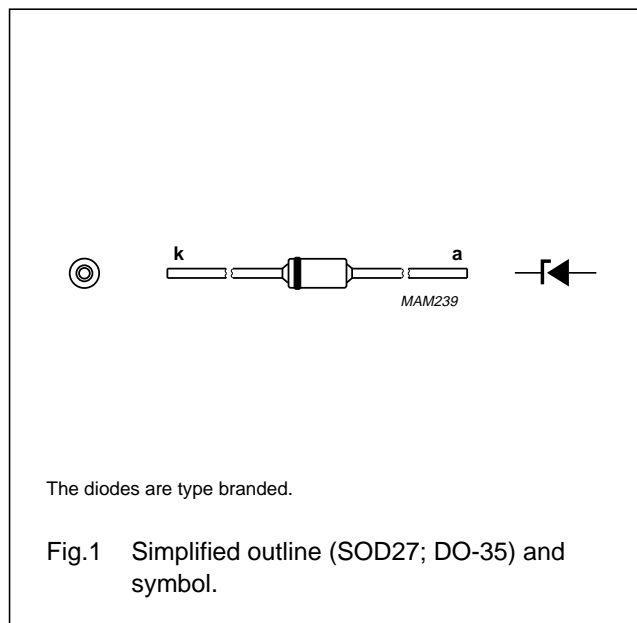
- Total power dissipation: max. 500 mW
- Two tolerance series: $\pm 2\%$, and approx. $\pm 5\%$
- Working voltage range: nom. 2.4 to 75 V (E24 range)
- Non-repetitive peak reverse power dissipation: max. 40 W.

APPLICATIONS

- Low voltage stabilizers or voltage references.

DESCRIPTION

Low-power voltage regulator diodes in hermetically sealed leaded glass SOD27 (DO-35) packages. The diodes are available in the normalized E24 $\pm 2\%$ (BZX79-B) and approx. $\pm 5\%$ (BZX79-C) tolerance range. The series consists of 37 types with nominal working voltages from 2.4 to 75 V.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_F	continuous forward current		–	250	mA
I_{ZSM}	non-repetitive peak reverse current	$t_p = 100 \mu\text{s}$; square wave; $T_j = 25 \text{ }^\circ\text{C}$ prior to surge	see Tables 1 and 2		A
P_{tot}	total power dissipation	$T_{amb} = 50 \text{ }^\circ\text{C}$; note 1	–	400	mW
		$T_{amb} = 50 \text{ }^\circ\text{C}$; note 2	–	500	mW
P_{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu\text{s}$; square wave; $T_j = 25 \text{ }^\circ\text{C}$ prior to surge; see Fig.3	–	40	W
T_{stg}	storage temperature		–65	+200	$^\circ\text{C}$
T_j	junction temperature		–65	+200	$^\circ\text{C}$

Notes

1. Device mounted on a printed circuit-board without metallization pad; lead length max.
2. Tie-point temperature $\leq 50 \text{ }^\circ\text{C}$; max. lead length 8 mm.

ELECTRICAL CHARACTERISTICS

Total BZX79-B and BZX79-C series

$T_j = 25 \text{ }^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V_F	forward voltage	$I_F = 10 \text{ mA}$; see Fig.4	0.9	V

Voltage regulator diodes

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SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
I_R	reverse current			
	BZX79-B/C2V4	$V_R = 1\text{ V}$	50	μA
	BZX79-B/C2V7	$V_R = 1\text{ V}$	20	μA
	BZX79-B/C3V0	$V_R = 1\text{ V}$	10	μA
	BZX79-B/C3V3	$V_R = 1\text{ V}$	5	μA
	BZX79-B/C3V6	$V_R = 1\text{ V}$	5	μA
	BZX79-B/C3V9	$V_R = 1\text{ V}$	3	μA
	BZX79-B/C4V3	$V_R = 1\text{ V}$	3	μA
	BZX79-B/C4V7	$V_R = 2\text{ V}$	3	μA
	BZX79-B/C5V1	$V_R = 2\text{ V}$	2	μA
	BZX79-B/C5V6	$V_R = 2\text{ V}$	1	μA
	BZX79-B/C6V2	$V_R = 4\text{ V}$	3	μA
	BZX79-B/C6V8	$V_R = 4\text{ V}$	2	μA
	BZX79-B/C7V5	$V_R = 5\text{ V}$	1	μA
	BZX79-B/C8V2	$V_R = 5\text{ V}$	700	nA
	BZX79-B/C9V1	$V_R = 6\text{ V}$	500	nA
	BZX79-B/C10	$V_R = 7\text{ V}$	200	nA
	BZX79-B/C11	$V_R = 8\text{ V}$	100	nA
	BZX79-B/C12	$V_R = 8\text{ V}$	100	nA
	BZX79-B/C13	$V_R = 8\text{ V}$	100	nA
BZX79-B/C15 to BZX79-B/C75	$V_R = 0.7V_{Znom}$	50	nA	

Voltage regulator diodes

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Table 1 Per type, BZX79-B/C2V4 to BZX79-B/C24

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified.

BZX79- Bxxx Cxxx	WORKING VOLTAGE V_Z (V) at $I_{Z\text{test}} = 5\text{ mA}$			DIFFERENTIAL RESISTANCE r_{dif} (Ω)						TEMP. COEFF. S_Z (mV/K) at $I_{Z\text{test}} = 5\text{ mA}$ (see Figs 5 and 6)			DIODE CAP. C_d (pF) at $f = 1\text{ MHz}$; $V_R = 0\text{ V}$	NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} (A) at $t_p = 100\text{ }\mu\text{s}$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	
	Tol. $\pm 2\%$ (B)		Tol. approx. $\pm 5\%$ (C)		at $I_{Z\text{test}} = 1\text{ mA}$		at $I_{Z\text{test}} = 5\text{ mA}$		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MAX.
	MIN.	MAX.	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.							
2V4	2.35	2.45	2.2	2.6	275	600	70	100	-3.5	-1.6	0	450	6.0		
2V7	2.65	2.75	2.5	2.9	300	600	75	100	-3.5	-2.0	0	450	6.0		
3V0	2.94	3.06	2.8	3.2	325	600	80	95	-3.5	-2.1	0	450	6.0		
3V3	3.23	3.37	3.1	3.5	350	600	85	95	-3.5	-2.4	0	450	6.0		
3V6	3.53	3.67	3.4	3.8	375	600	85	90	-3.5	-2.4	0	450	6.0		
3V9	3.82	3.98	3.7	4.1	400	600	85	90	-3.5	-2.5	0	450	6.0		
4V3	4.21	4.39	4.0	4.6	410	600	80	90	-3.5	-2.5	0	450	6.0		
4V7	4.61	4.79	4.4	5.0	425	500	50	80	-3.5	-1.4	0.2	300	6.0		
5V1	5.00	5.20	4.8	5.4	400	480	40	60	-2.7	-0.8	1.2	300	6.0		
5V6	5.49	5.71	5.2	6.0	80	400	15	40	-2.0	1.2	2.5	300	6.0		
6V2	6.08	6.32	5.8	6.6	40	150	6	10	0.4	2.3	3.7	200	6.0		
6V8	6.66	6.94	6.4	7.2	30	80	6	15	1.2	3.0	4.5	200	6.0		
7V5	7.35	7.65	7.0	7.9	30	80	6	15	2.5	4.0	5.3	150	4.0		
8V2	8.04	8.36	7.7	8.7	40	80	6	15	3.2	4.6	6.2	150	4.0		
9V1	8.92	9.28	8.5	9.6	40	100	6	15	3.8	5.5	7.0	150	3.0		
10	9.80	10.20	9.4	10.6	50	150	8	20	4.5	6.4	8.0	90	3.0		
11	10.80	11.20	10.4	11.6	50	150	10	20	5.4	7.4	9.0	85	2.5		
12	11.80	12.20	11.4	12.7	50	150	10	25	6.0	8.4	10.0	85	2.5		
13	12.70	13.30	12.4	14.1	50	170	10	30	7.0	9.4	11.0	80	2.5		
15	14.70	15.30	13.8	15.6	50	200	10	30	9.2	11.4	13.0	75	2.0		
16	15.70	16.30	15.3	17.1	50	200	10	40	10.4	12.4	14.0	75	1.5		
18	17.60	18.40	16.8	19.1	50	225	10	45	12.4	14.4	16.0	70	1.5		
20	19.60	20.40	18.8	21.2	60	225	15	55	12.3	15.6	18.0	60	1.5		
22	21.60	22.40	20.8	23.3	60	250	20	55	14.1	17.6	20.0	60	1.25		
24	23.50	24.50	22.8	25.6	60	250	25	70	15.9	19.6	22.0	55	1.25		

Voltage regulator diodes

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Table 2 Per type, BZX79-B/C27 to BZX79-B/C75
 $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified.

BZX79- Bxxx Cxxx	WORKING VOLTAGE V_z (V) at $I_{ztest} = 2\text{ mA}$			DIFFERENTIAL RESISTANCE r_{dif} (Ω)						TEMP. COEFF. S_z (mV/K) at $I_{ztest} = 2\text{ mA}$ (see Figs 5 and 6)			DIODE CAP. C_d (pF) at $f = 1\text{ MHz}$; $V_R = 0\text{ V}$	NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} (A) at $t_p = 100\text{ }\mu\text{s}$; $T_{amb} = 25\text{ }^\circ\text{C}$
	Tol. $\pm 2\%$ (B)			at $I_{ztest} = 0.5\text{ mA}$			at $I_{ztest} = 2\text{ mA}$			MIN.	TYP.	MAX.		
	MIN.	MAX.	Tol. approx. $\pm 5\%$ (C)	TYP.	MAX.	TYP.	MAX.	MIN.	TYP.					
27	26.50	27.50	25.1	28.9	28.9	25.1	28.9	25.1	28.9	25.3	25.3	50	1.0	
30	29.40	30.60	28.0	32.0	30.0	30.0	32.0	30.0	32.0	29.4	29.4	50	1.0	
33	32.30	33.70	31.0	35.0	32.5	35.0	35.0	35.0	35.0	33.4	33.4	45	0.9	
36	35.30	36.70	34.0	38.0	35.0	38.0	38.0	38.0	38.0	37.4	37.4	45	0.8	
39	38.20	39.80	37.0	41.0	35.0	41.0	41.0	41.0	41.0	41.2	41.2	45	0.7	
43	42.10	43.90	40.0	46.0	37.5	46.0	46.0	46.0	46.0	46.6	46.6	40	0.6	
47	46.10	47.90	44.0	50.0	37.5	50.0	50.0	50.0	50.0	51.8	51.8	40	0.5	
51	50.00	52.00	48.0	54.0	40.0	54.0	54.0	54.0	54.0	57.2	57.2	40	0.4	
56	54.90	57.10	52.0	60.0	42.5	60.0	60.0	60.0	60.0	63.8	63.8	40	0.3	
62	60.80	63.20	58.0	66.0	45.0	66.0	66.0	66.0	66.0	71.6	71.6	35	0.3	
68	66.60	69.40	64.0	72.0	47.5	72.0	72.0	72.0	72.0	79.8	79.8	35	0.25	
75	73.50	76.50	70.0	79.0	50.0	79.0	79.0	79.0	79.0	88.6	88.6	35	0.2	

Voltage regulator diodes

BZX79 series

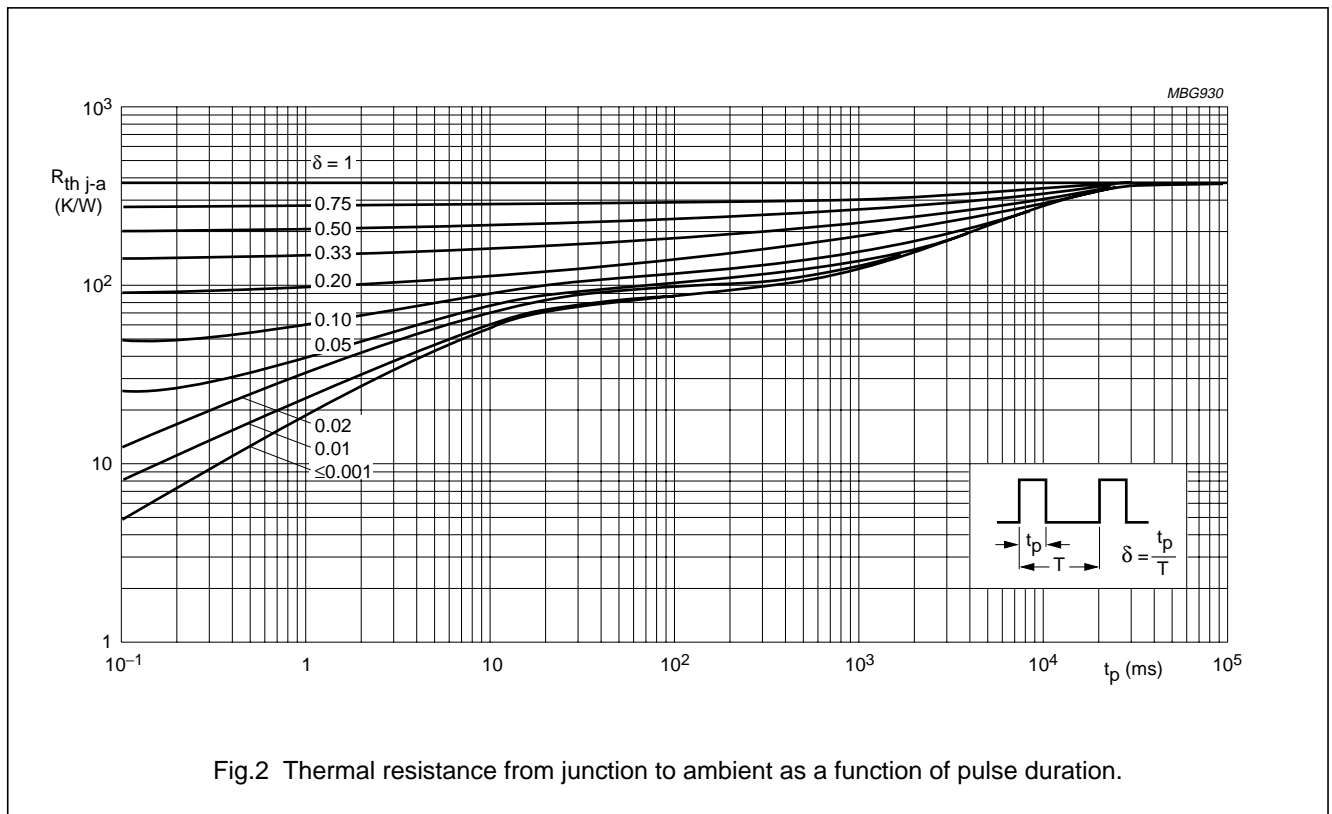
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-t_p}$	thermal resistance from junction to tie-point	lead length 8 mm.	300	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length max.; see Fig.2 and note 1	380	K/W

Note

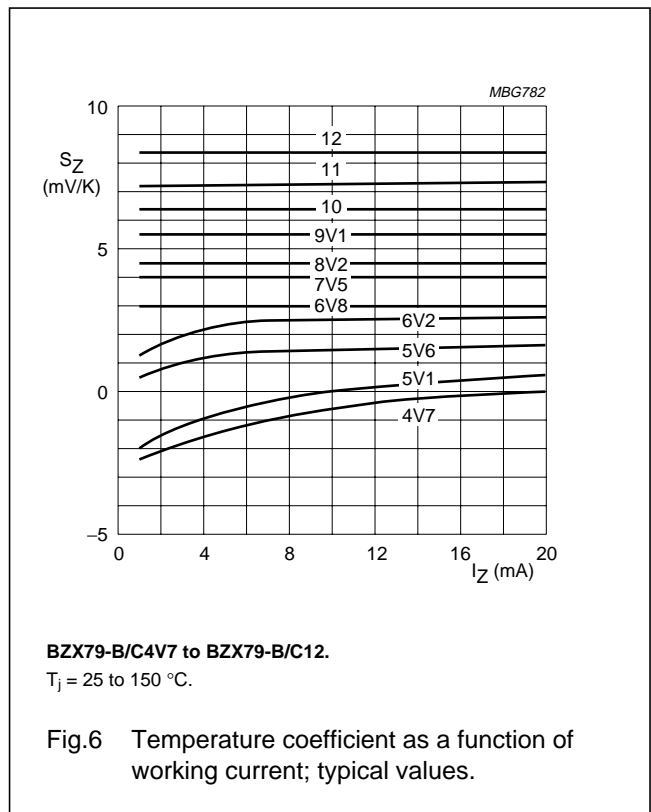
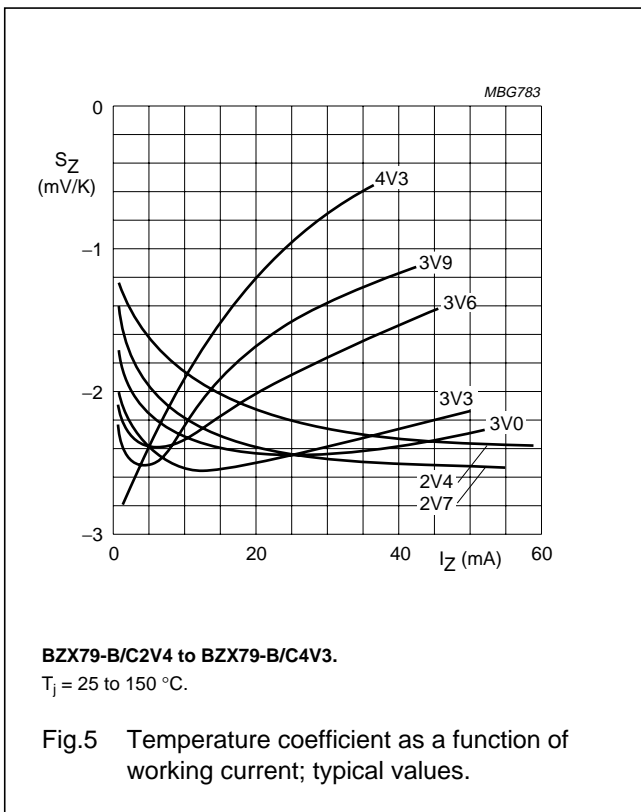
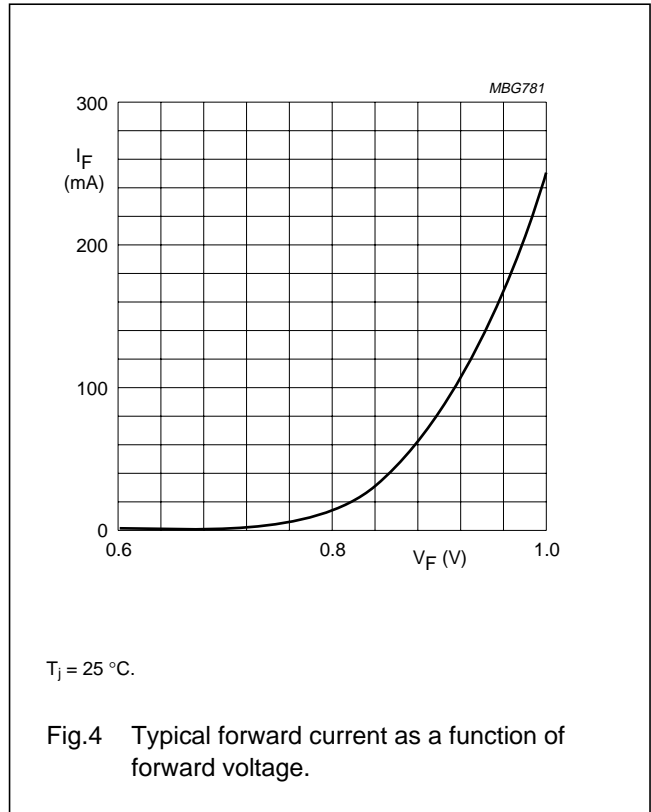
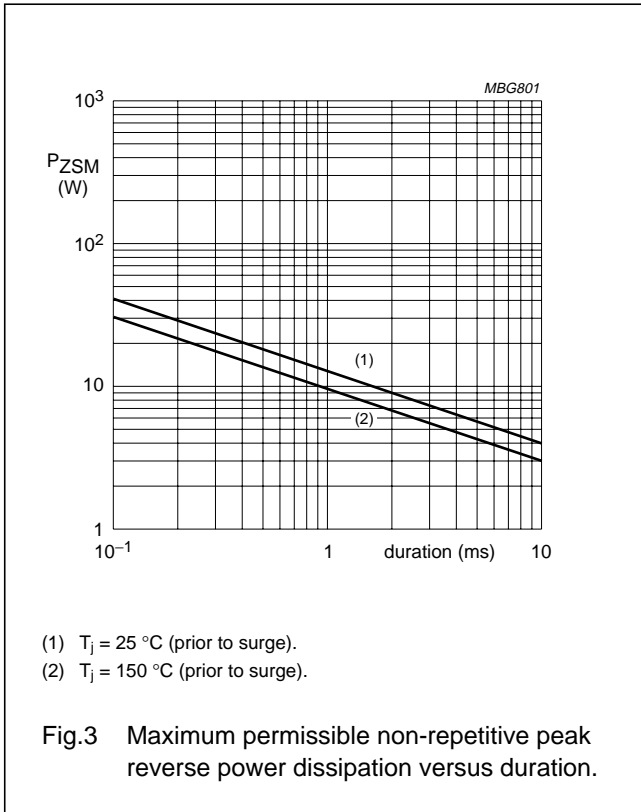
1. Device mounted on a printed circuit-board without metallization pad.

GRAPHICAL DATA



Voltage regulator diodes

BZX79 series



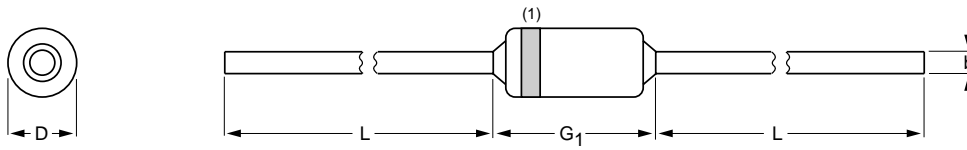
Voltage regulator diodes

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PACKAGE OUTLINE

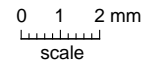
Hermetically sealed glass package; axial leaded; 2 leads

SOD27



DIMENSIONS (mm are the original dimensions)

UNIT	b max.	D max.	G ₁ max.	L min.
mm	0.56	1.85	4.25	25.4



Note

1. The marking band indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD27	A24	DO-35	SC-40			97-06-09

Voltage regulator diodes

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NOTES

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NOTES

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